2N7002L, 2V7002L

Small Signal MOSFET

60 V, 115 mA, N-Channel SOT-23

Features

- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable (2V7002L)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	60	Vdc
Drain–Gate Voltage (R_{GS} = 1.0 M Ω)	V _{DGR}	60	Vdc
Drain Current – Continuous T _C = 25°C (Note 1) T _C = 100°C (Note 1) – Pulsed (Note 2)	I _D I _D I _{DM}	±115 ±75 ±800	mAdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR–5 Board (Note 3) T _A = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	P _D R _{θJA}	225 1.8 556	mW mW/°C °C/W
Total Device Dissipation (Note 4) Alumina Substrate, T _A = 25°C Derate above 25°C Thermal Resistance, Junction-to-Ambient	P _D R _{θJA}	300 2.4 417	mW mW/°C °C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

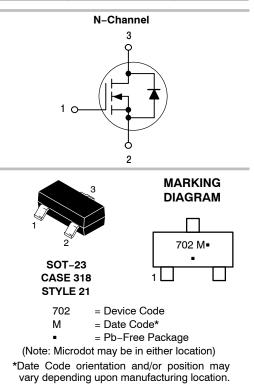
- 1. The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.
- 3. FR-5 = 1.0 x 0.75 x 0.062 in.
- 4. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.



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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
60 V	7.5 Ω @ 10 V, 500 mA	115 mA



ORDERING INFORMATION

Device	Package	Shipping [†]		
2N7002LT1G	SOT-23	3000 Tape & Reel		
2N7002LT3G	(Pb-Free)	10,000 Tape & Reel		
2V7002LT1G		3000 Tape & Reel		
2V7002LT3G	SOT-23	10,000 Tape & Reel		
2N7002LT1H*	(Pb-Free)	3000 Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*Not for new design.

2N7002L, 2V7002L

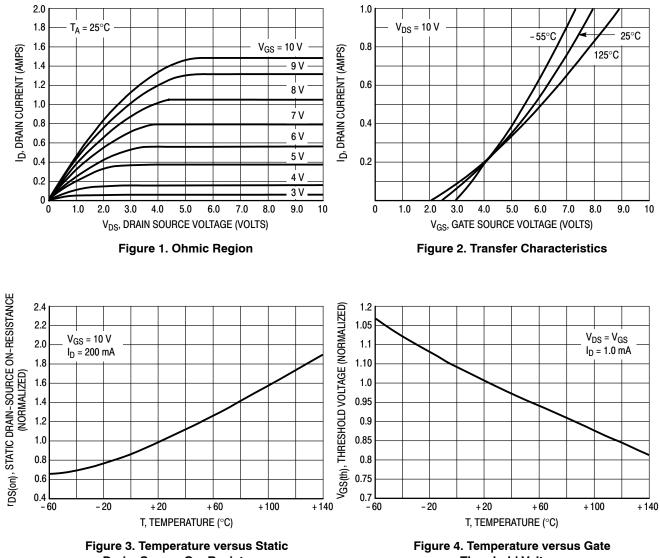
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain–Source Breakdown Voltage (V_{GS} = 0, I _D = 10 µAdc)	V _{(BR)DSS}	60	-	-	Vdc
$ \begin{array}{ll} \mbox{Zero Gate Voltage Drain Current} & T_J = 25^\circ C \\ (V_{GS} = 0, V_{DS} = 60 Vdc) & T_J = 125^\circ C \end{array} $	I _{DSS}	-		1.0 500	μAdc
Gate-Body Leakage Current, Forward (V _{GS} = 20 Vdc)	I _{GSSF}	-	-	100	nAdc
Gate-Body Leakage Current, Reverse (V _{GS} = -20 Vdc)	I _{GSSR}	_	-	-100	nAdc
ON CHARACTERISTICS (Note 5)			•		•
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$	V _{GS(th)}	1.0	-	2.5	Vdc
$ \begin{array}{l} On-State \ Drain \ Current \\ (V_{DS} \geq 2.0 \ V_{DS(on)}, \ V_{GS} = 10 \ Vdc) \end{array} $	I _{D(on)}	500	-	-	mA
$\begin{array}{l} \text{Static Drain-Source On-State Voltage} \\ (\text{V}_{\text{GS}} = 10 \text{ Vdc}, \text{ I}_{\text{D}} = 500 \text{ mAdc}) \\ (\text{V}_{\text{GS}} = 5.0 \text{ Vdc}, \text{ I}_{\text{D}} = 50 \text{ mAdc}) \end{array}$	V _{DS(on)}	- -		3.75 0.375	Vdc
$ \begin{array}{ll} \mbox{Static Drain-Source On-State Resistance} \\ (V_{GS} = 10 \mbox{ V}, \mbox{ I}_D = 500 \mbox{ mAdc}) & T_C = 25^\circ C \\ (V_{GS} = 5.0 \mbox{ Vdc}, \mbox{ I}_D = 50 \mbox{ mAdc}) & T_C = 125^\circ C \\ T_C = 125^\circ C \\ T_C = 125^\circ C \end{array} $	r _{DS(on)}	- - -	_ _ _	7.5 13.5 7.5 13.5	Ohms
Forward Transconductance $(V_{DS} \ge 2.0 V_{DS(on)}, I_D = 200 \text{ mAdc})$	9 _{FS}	80	-	-	mS
DYNAMIC CHARACTERISTICS					
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{iss}	_	-	50	pF
Output Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C _{oss}	-	-	25	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$	C _{rss}	-	-	5.0	pF
SWITCHING CHARACTERISTICS (Note 5)					
Turn-On Delay Time $(V_{DD} = 25 \text{ Vdc}, I_D \cong 500 \text{ mAdc},$	t _{d(on)}	-	-	20	ns
Turn–Off Delay Time $R_G = 25 \Omega$, $R_L = 50 \Omega$, $V_{gen} = 10 V$)	t _{d(off)}	-	-	40	ns
BODY-DRAIN DIODE RATINGS					
Diode Forward On-Voltage (I _S = 11.5 mAdc, V _{GS} = 0 V)	V _{SD}	-	-	-1.5	Vdc
Source Current Continuous (Body Diode)	I _S	-	-	-115	mAdc
Source Current Pulsed	I _{SM}	-	-	- 800	mAdc
	•				•

5. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

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TYPICAL ELECTRICAL CHARACTERISTICS

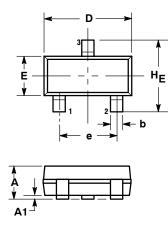


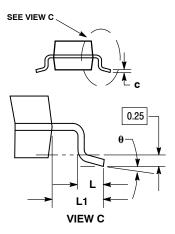
Drain-Source On-Resistance

Threshold Voltage

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**





NOTES

STYLE 21: PIN 1. GATE

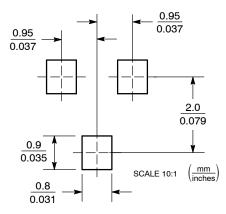
2. 3. SOURCE

DRAIN

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 1. CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH 2
- 3. THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4

NUL INSTERO							
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
С	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	
θ	0°		10°	0°		10°	

SOLDERING FOOTPRINT



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